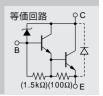
## サージ<mark>電</mark>圧吸収 ダーリントン

## 2SD2141

(Ta = 25)



シリコンNPN三重拡散プレーナ型トランジスタ

## **用途:**イグナイタ、ソレノイド、モータ駆動、一般用

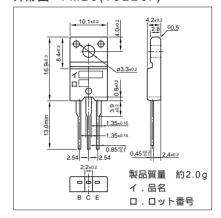
絶対最大定格 (Ta = 25 )

記号	規 格 値	単 位	
Vсво	$380 \pm 50$	V	
VCEO	$380 \pm 50$	V	
VEBO	6	V	
Ic	6(パルス10)	Α	
Ів	1	Α	
Pc	35(Tc = 25 )	W	
Tj	150		
Tstg	- 55 ~ + 150		

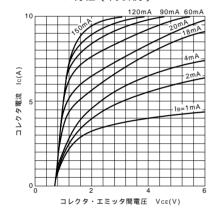
電気的特性

記 号	試 験 条 件	規 格 値	単位
Ісво	Vcb = 330V	10max	μΑ
<b>І</b> ЕВО	VEB = 6V	20max	mA
V(BR)CEO	Ic = 25mA	330 ~ 430	V
hfE	Vce = 2V, Ic = 3A	1500min	
Vce(sat)	Ic = 4A, IB = 20mA	1.5max	V
fτ	VcE = 12V, IE = - 0.5A	20typ	MHz
Сов	VcB = 10V, f = 1MHz	95typ	pF

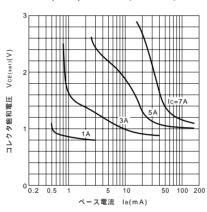
外形図 FM20(T0220F)



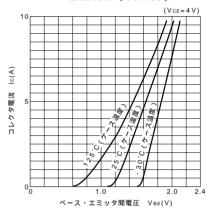
Ic-VcE特性(代表例)



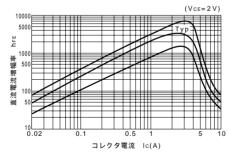
VcE(sat)-IB特性(代表例)



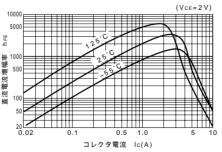
Ic-VBE温度特性(代表例)



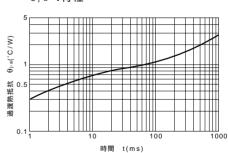
hfe-Ic特性(代表例)



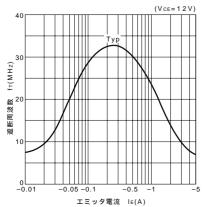
hfe-Ic温度特性(代表例)



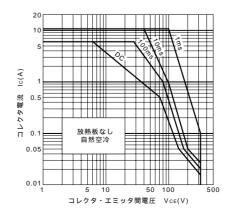
θ<sub>j-a</sub>-t特性



f⊤−Iε特性(代表例)



ASO曲線(単発パルス)



Pc−Ta定格

